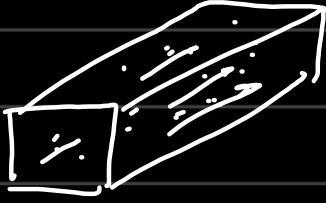
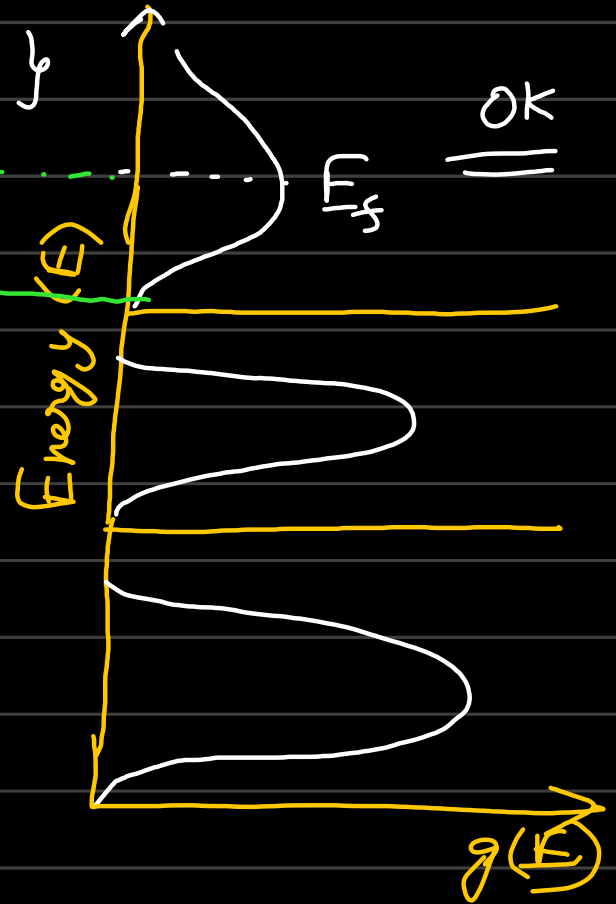
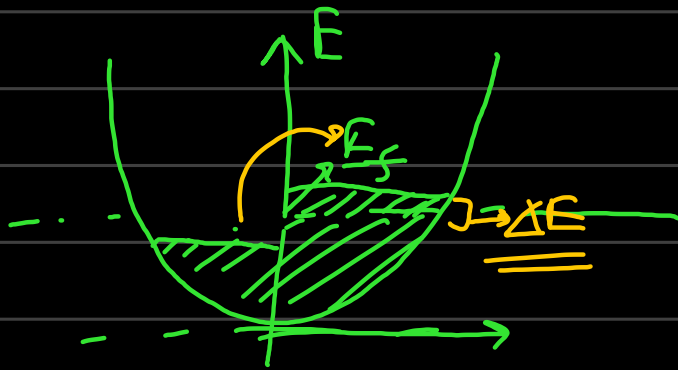
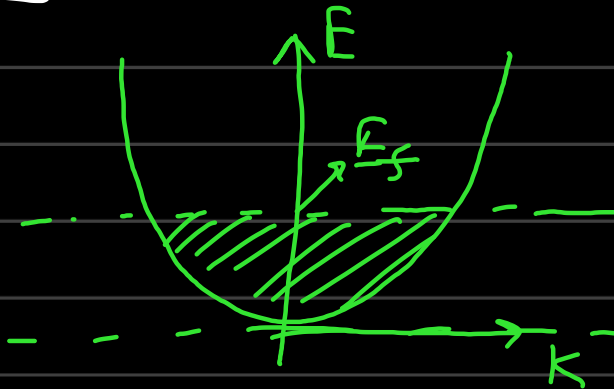


Quantum Conduction

→ Classical Conductivity: $\sigma = \frac{ne^2\tau}{m}$



Total no. of e^-
in volume



Modern theory for Solids:

Quantum Conductivity:

$$\boxed{\sigma = e^2 \tau \cdot v_f^2 g(E_f)}$$

↳ Classical theory cannot explain -ve Hall coefficients and linear resistivity vs temperature relation

$$v_f^2 g(E_f) \approx \frac{n}{m}$$

$$v^2 \approx \frac{kF}{m} \Rightarrow \boxed{\frac{kF}{m} g(E_f) = \frac{n}{m}}$$

→ Not all electrons contribute to conductivity in solids.

→ density of states at fermi level dictates conductivity of solids.

Semiconductors:

↳ clear gap in Density of States.

↳ Clear gap b/w B_o & A_{BO} orbitals.

* A completely filled band will not conduct.

↳ no immediate energy level above fermi level.

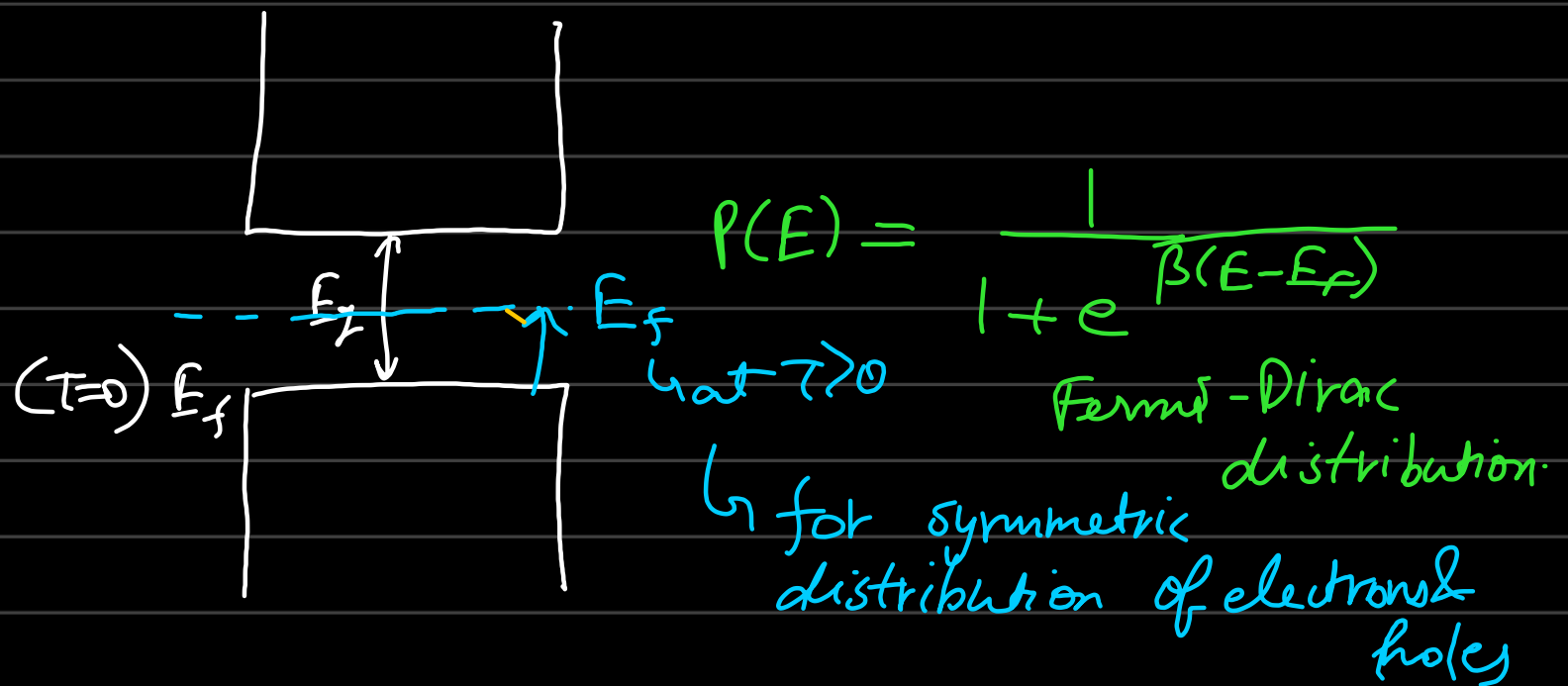
→ $\sigma_{\text{semiconductor}} = 0$ at $0K$

→ $\sigma_{\text{semi}} > 0$ at $T > 0K$ → excitation

→ Electron-hole pair creation:

↳ Thermal energy or EM photon incidence.

Carrier statistics in semiconductors:



→ Fermion & Boson:

f — 0, 1 { only two e^- per state }

b — 0, 1, 2, 3, ... ∞ { all photons can fall down to the ground state }

Intrinsic Semiconductor:

→ At any non-zero temp. The conduction band always has non-zero probability of occupation.

$$n_i = \int_{E_C}^{\infty} P(E) D(E) dE$$

→ Typical semiconductors have very small carrier density : $10^6 - 10^{15} / \text{cm}^3$

→ at any given time steady state density is $10^6 - 10^{13} / \text{cm}^3$ of electrons.

→ Conduction in semiconductors, is due to both electrons & holes.

$$\sigma_{\text{semi}} = \frac{ne^2\tau}{m} = ne\mu_n + pe\mu_p$$

$$\mu_n = \frac{e\tau_n}{m_e}$$

mobility of electrons

$$\mu_p = \frac{e\tau_p}{m_h}$$

mobility of holes.

$$m = m_0 m_{\text{eff}}$$

rest mass

$$(9.1 \times 10^{-31} \text{ kg})$$

scaling factor.

→ electron does not move freely in a periodic potential.

$$E = \frac{\hbar^2 k^2}{2m}$$

$$\rightarrow m = \frac{2E}{\hbar^2 k^2}$$

$$\Rightarrow \frac{\partial E}{\partial k^2} = \frac{\hbar^2}{m}$$

$$m = \frac{\hbar^2}{\partial E / \partial k^2}$$

